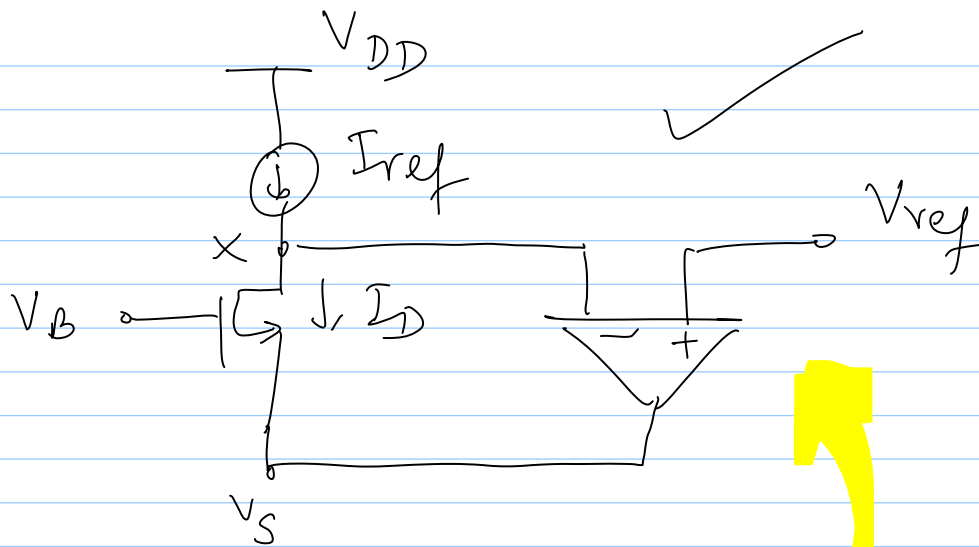
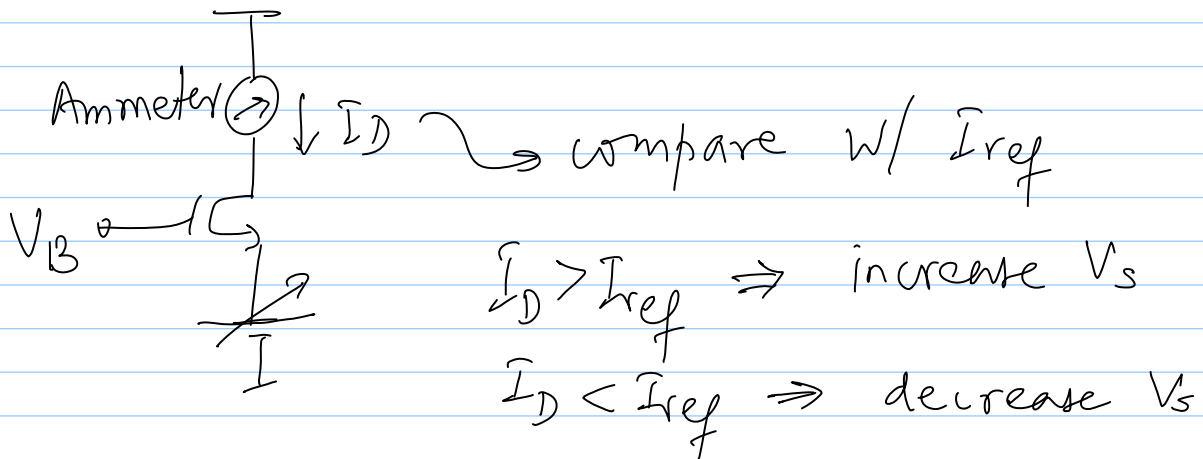


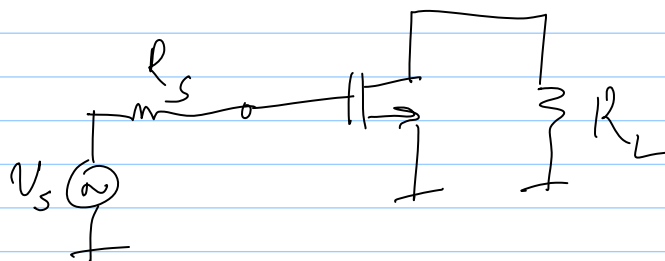
21-9-12

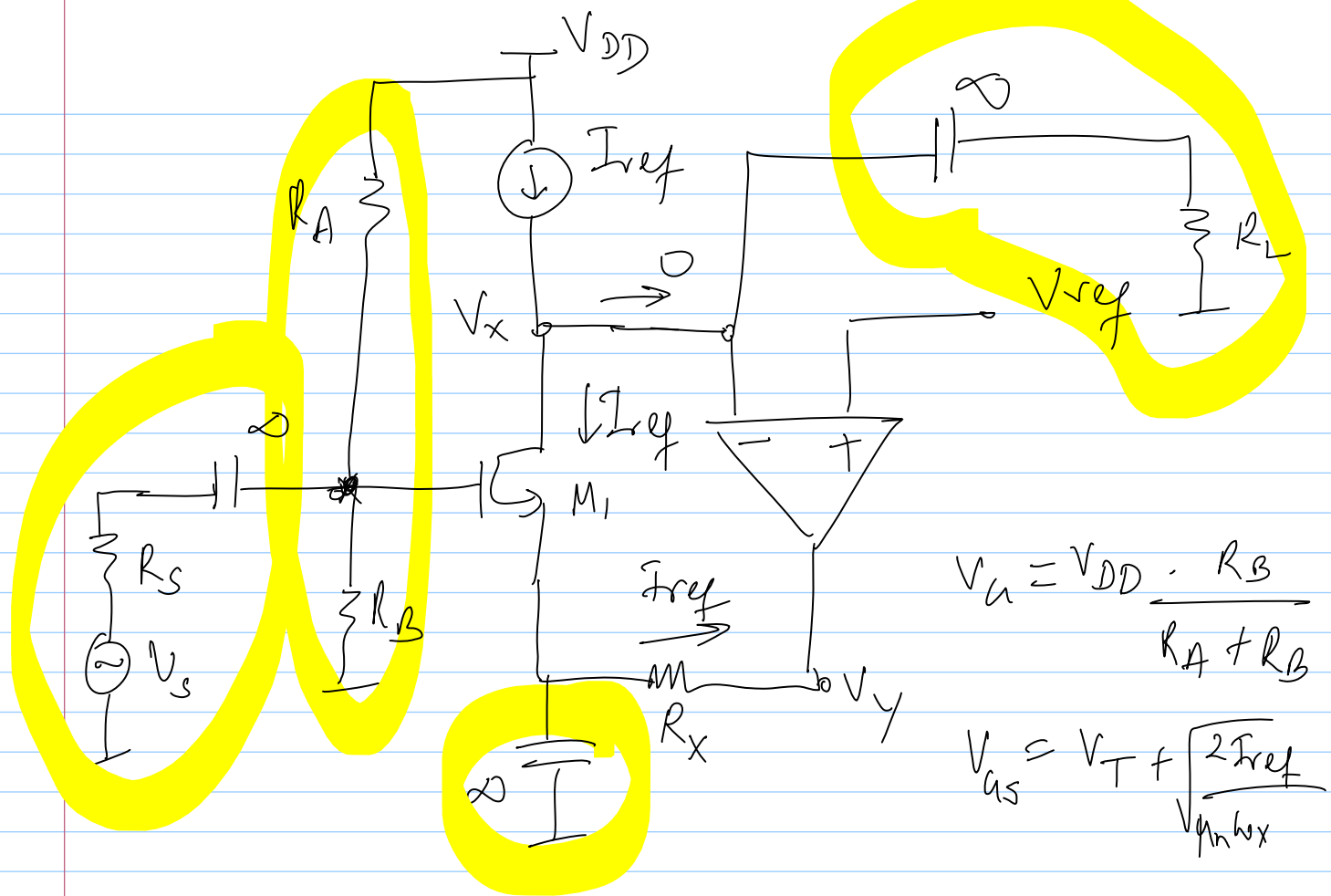
Lec 23

<u>case 1</u>	—	measure I_D	, change V_a
2	—	" I_s	" V_s
<u>case 3</u>	—	" I_D	" V_s



$$V_{ref} \geq V_B - V_T$$





$$V_a = V_{DD} \cdot \frac{R_B}{R_A + R_B}$$

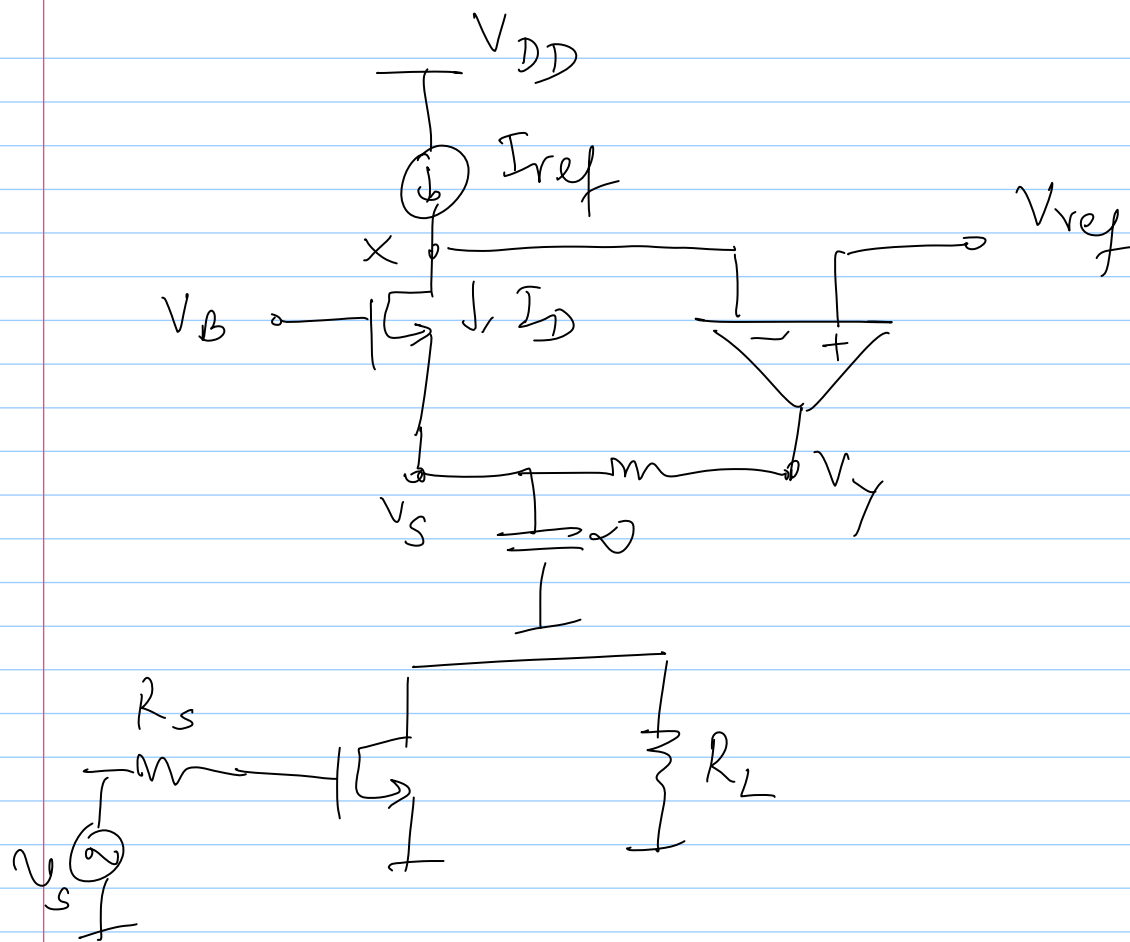
$$V_{as} = V_T + \sqrt{\frac{2 I_{ref}}{\mu_{n,ox} \left(\frac{W}{L} \right)}}$$

$$V_a = V_{DD} \cdot \frac{R_B}{R_A + R_B}$$

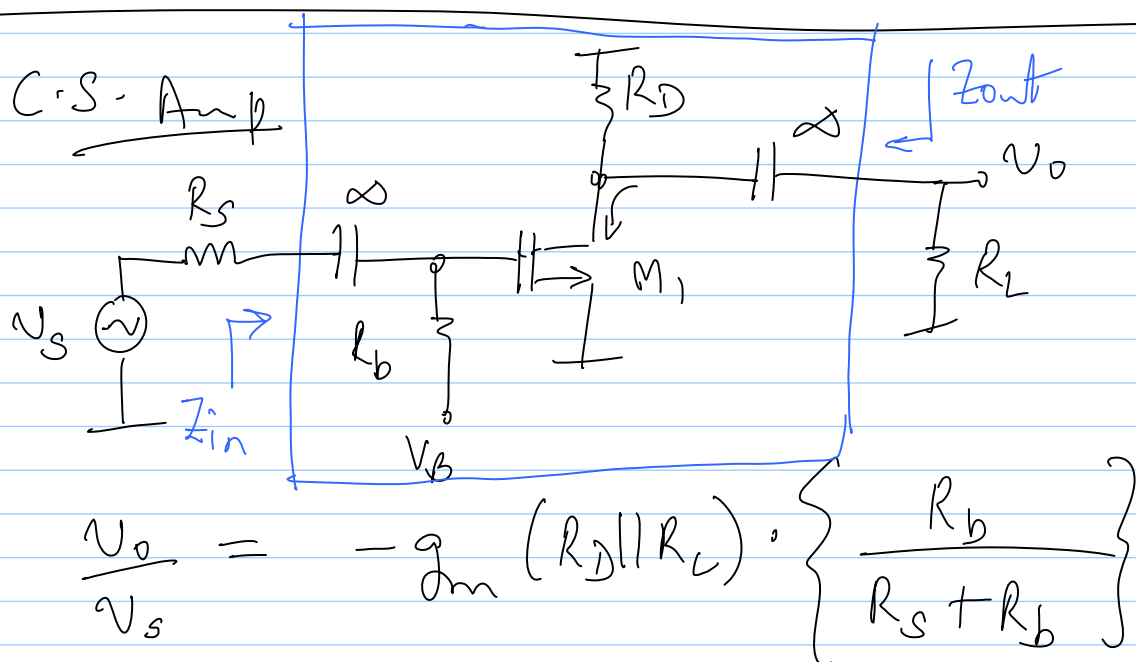
$$V_{as} = V_T + \sqrt{\frac{2 I_{ref}}{\mu_{n,ox} \left(\frac{W}{L} \right)}}$$

$$V_s = V_a - V_{as} = \frac{V_{DD} R_B}{R_A + R_B} - V_T - \sqrt{\frac{2 I_{ref}}{\mu_{n,ox} \left(\frac{W}{L} \right)}}$$

$$V_y = V_s - I_{ref} R_X$$



Case 4 : measure I_s feedback V_a) H.W.



ideal VCVS

$$Z_{in} = \infty$$

$$Z_{out} = 0$$

CS Amp

$$Z_{in} = R_b$$

$$\uparrow R_b$$

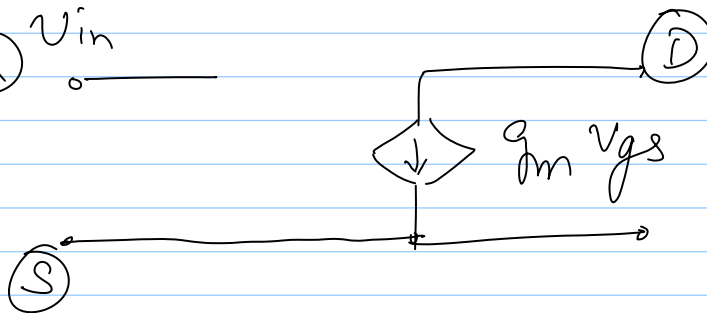
$$Z_{out} = R_D$$

$$R_D \rightarrow 0 \Rightarrow g_{mn} = 0$$

ideal VCVS

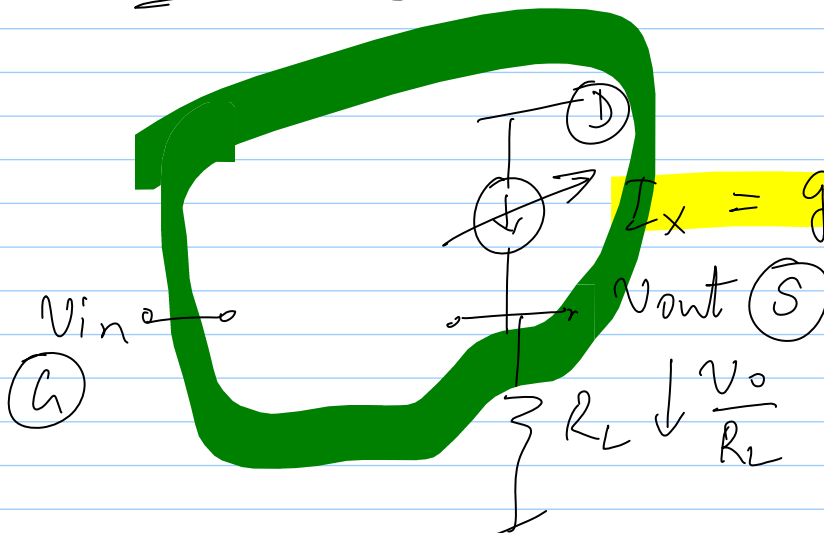
MOSFET

$$\textcircled{G} V_{in}$$



$$g_m \rightarrow \infty$$

VCVS = 1



$$V_{out} = V_{in}$$

$$(g_m \rightarrow \infty)$$

$$I_x = g_m (V_{in} - V_{out})$$

* measure V_{in} , V_{out}

* change V_{out}

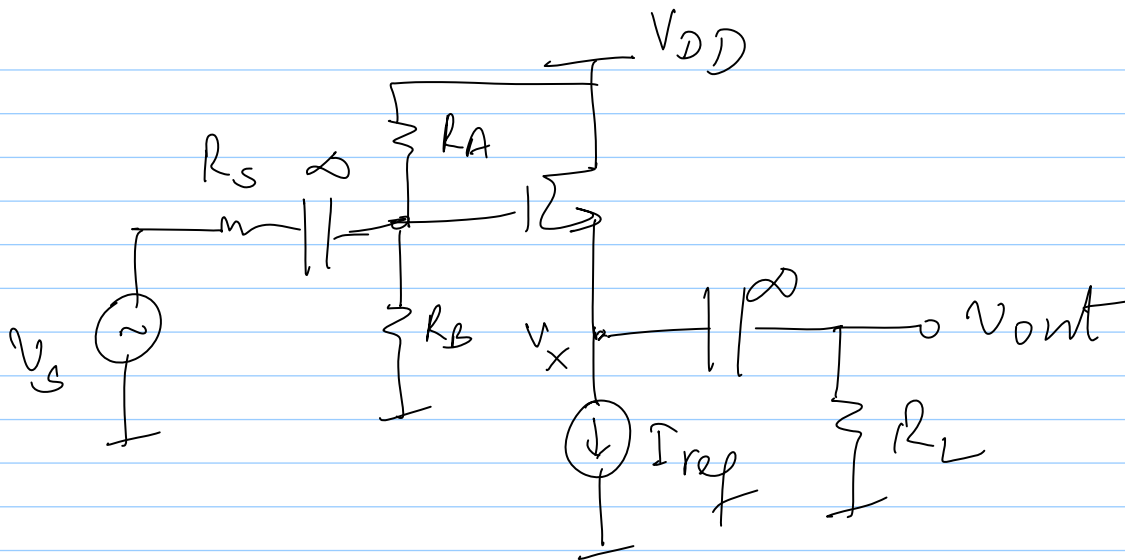
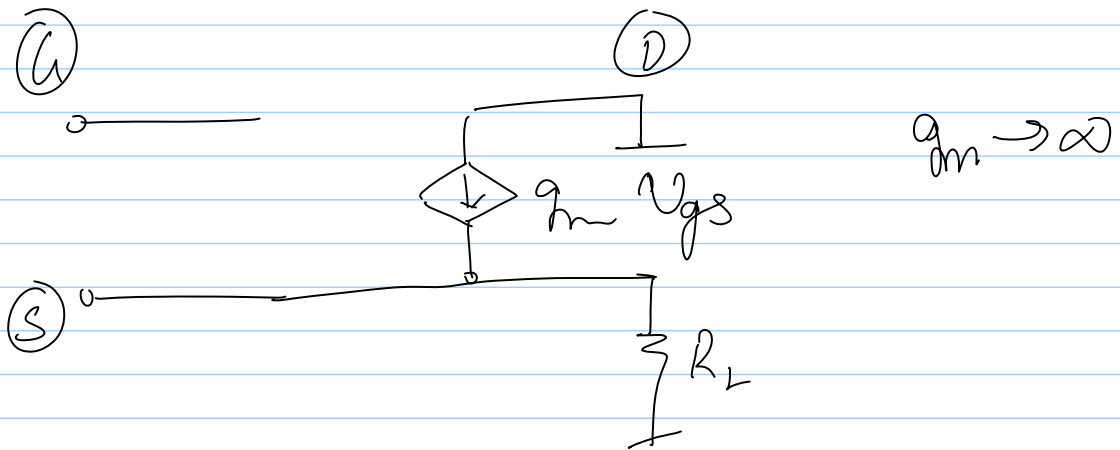
* If $V_{out} > V_{in} \Rightarrow$ reduce I_x

$V_{out} < V_{in} \Rightarrow$ increase I_x

* comparison $\Rightarrow (V_{in} - V_{out})$

$$\frac{v_{out}}{R_L} = g_m (v_{in} - v_{out})$$

$$v_{in} = v_{out} \Rightarrow g_m \rightarrow \infty$$



$$V_x = \frac{V_{DD} R_B}{R_A + R_B} - V_T - \sqrt{\frac{2 I_{ref}}{\mu_n C_{ox} \left(\frac{W}{L} \right)}}$$